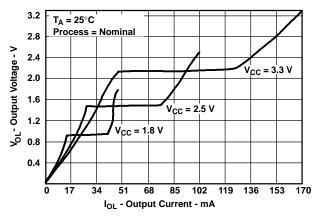
#### **FEATURES**

- Member of the Texas Instruments Widebus™
  Family
- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- DOC™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With  $I_{OH}$  and  $I_{OL}$  of  $\pm 24$  mA at 2.5-V  $V_{CC}$

- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Package Options Include Plastic Thin Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

### **DESCRIPTION**

A Dynamic Output Control (DOC<sup>TM</sup>) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical  $V_{OL}$  vs  $I_{OL}$  and  $V_{OH}$  vs  $I_{OH}$  curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number SCEA006, and *Dynamic Output Control (DOC*<sup>TM</sup>) *Circuitry Technology and Applications*, literature number SCEA009.



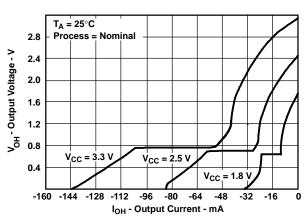


Figure 1. Output Voltage vs Output Current

This 12-bit to 24-bit registered bus exchanger is operational at 1.2-V to 3.6-V  $V_{CC}$ , but is designed specifically for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74AVC16269 is used in applications in which two separate ports must be multiplexed onto, or demultiplexed from, a single port. The device is particularly suitable as an interface between synchronous DRAMs and high-speed microprocessors.

Data is stored in the internal B-port registers on the low-to-high transition of the clock (CLK) input when the appropriate clock-enable (CLKENA) inputs are low. Proper control of these inputs allows two sequential 12-bit words to be presented as a 24-bit word on the B port. For data transfer in the B-to-A direction, a single storage register is provided. The select (SEL) line selects 1B or 2B data for the A outputs. The register on the A output permits the fastest possible data transfer, thus extending the period during which the data is valid on the bus.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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## **DESCRIPTION (CONTINUED)**

The control terminals are registered so that all transactions are synchronous with CLK. Data flow is controlled by the active-low output enables ( $\overline{OEA}$ ,  $\overline{OEB1}$ ,  $\overline{OEB2}$ ).

To ensure the high-impedance state during power up or power down, a clock pulse should be applied as soon as possible, and  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. Due to  $\overline{OE}$  being routed through a register, the active state of the outputs cannot be determined prior to the arrival of the first clock pulse.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16269 is characterized for operation from -40°C to 85°C.

#### **TERMINAL ASSIGNMENTS**

## DGG OR DGV PACKAGE (TOP VIEW)

	_			1
OEA	┨╸	$\cup$	56	OEB2
	2			CLKENA2
2B3				2B4
GND				GND
2B2				2B5
2B1				2B6
V <sub>CC</sub>				V <sub>CC</sub>
A1	Ä,			2B7
A2				2B8
	10			2B9
GND				GND
	12			2B10
	13			2B11
	14			2B12
	15			1B12
	16			1B11
	17			1B10
GND				GND
A10				1B9
A11				1B8
A12			36	
$V_{CC}$				$v_{cc}$
	23		34	
1B2			33	1B5
GND	25			GND
1B3				1B4
NC	27		30	
SEL	28		29	]CLK

NC - No internal connection



## **FUNCTION TABLES**

### **OUTPUT ENABLE**

	INPUTS	OUTPUTS			
CLK	OEA	OEB	Α	1B, 2B	
1	Н	Н	Z	Z	
$\uparrow$	Н	L	Z	Active	
$\uparrow$	L	Н	Active	Z	
$\uparrow$	L	L	Active	Active	

## A-TO-B STORAGE (OEB = L)

	INPUTS							
CLKENA1	CLKENA2	CLK	Α	1B	2B			
Н	Н	Х	Х	1B <sub>0</sub> <sup>(1)</sup>	2B <sub>0</sub> <sup>(1)</sup>			
L	X	$\uparrow$	L	L	Χ			
L	X	$\uparrow$	Н	Н	Χ			
X	L	$\uparrow$	L	X	L			
X	L	$\uparrow$	Н	X	Н			

(1) Output level before the indicated steady-state input conditions were established

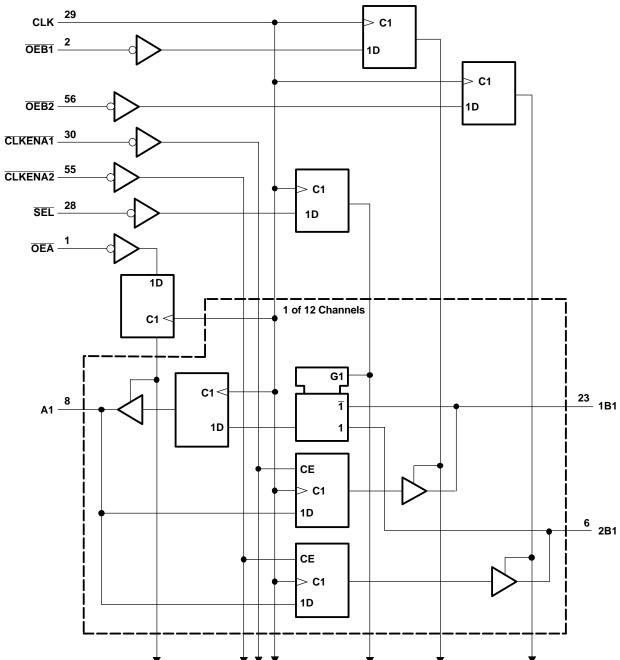
## B-TO-A STORAGE $(\overline{OEA} = L)$

	INP	UTS		OUTPUT
CLK	SEL	1B	2B	Α
Х	Н	Χ	Χ	A <sub>0</sub> <sup>(1)</sup>
X	L	Χ	Χ	A <sub>0</sub> <sup>(1)</sup> A <sub>0</sub> <sup>(1)</sup>
1	Н	L	Χ	L
1	Н	Н	Χ	Н
1	L	Χ	L	L
1	L	Χ	Н	Н

(1) Output level before the indicated steady-state input conditions were established



## LOGIC DIAGRAM (POSITIVE LOGIC)





## SN74AVC16269 12-BIT TO 24-BIT REGISTERED BUS EXCHANGER WITH 3-STATE OUTPUTS

SCES152G-DECEMBER 1998-REVISED MAY 2005

## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
$V_{I}$	Input voltage range <sup>(2)</sup>		-0.5	4.6	V
Vo	Voltage range applied to any input/output when the output is in the high-impedance or po	-0.5	4.6	V	
Vo	Voltage range applied to any input/output when	the output is in the high or low state (2)(3)	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V <sub>CC</sub> or GND			±100	mA
0	Package thermal impedance <sup>(4)</sup>	DGG package		64	°C/W
$\theta_{JA}$	гаскаде шеннаі шредансе( <sup>ч)</sup>	DGV package		48	C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>2)</sup> The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51.

## SN74AVC16269 12-BIT TO 24-BIT REGISTERED BUS EXCHANGER WITH 3-STATE OUTPUTS





## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V	Supply voltage	Operating	1.4	3.6	V
$V_{CC}$	Supply voltage	Data retention only	1.2		V
		V <sub>CC</sub> = 1.2 V	V <sub>CC</sub>		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	$0.65 \times V_{CC}$		
$V_{IH}$	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		
		V <sub>CC</sub> = 1.2 V		GND	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		$0.35 \times V_{CC}$	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
		V <sub>CC</sub> = 3 V to 3.6 V		0.8	
$V_{I}$	Input voltage		0	3.6	٧
V	Output voltage	Active state	0	$V_{CC}$	V
Vo	Output voltage	3-state	0	3.6	V
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-2	
	Static high-level output current (2)	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-4	mA
I <sub>OHS</sub>	Static high-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	ША
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-12	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2	
	Static low-level output current <sup>(2)</sup>	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		4	mA
I <sub>OLS</sub>	Static low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	MA
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		12	
Δt/Δν	Input transition rise or fall rate	V <sub>CC</sub> = 1.4 V to 3.6 V		5	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. Dynamic drive capability is equivalent to standard outputs with  $I_{OH}$  and  $I_{OL}$  of  $\pm 24$  mA at 3.3-V  $V_{CC}$ . See Figure 1 for  $V_{OL}$  vs  $I_{OL}$  and  $V_{OH}$  vs  $I_{OH}$  characteristics. Refer to the TI application reports, AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOCTM) Circuitry Technology and Applications, literature number SCEA009.



### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

F	PARAMETER	TEST CO	NDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT	
		$I_{OHS} = -100 \mu A$		1.4 V to 3.6 V	V <sub>CC</sub> - 0.2				
V <sub>OH</sub>		$I_{OHS} = -2 \text{ mA},$	V <sub>IH</sub> = 0.91 V	1.4 V	1.05				
		$I_{OHS} = -4 \text{ mA},$	V <sub>IH</sub> = 1.07 V	1.65 V	1.2			V	
		$I_{OHS} = -8 \text{ mA},$	$V_{IH} = 1.7 V$	2.3 V	1.75				
		$I_{OHS} = -12 \text{ mA},$	$V_{IH} = 2 V$	3 V	2.3				
		$I_{OLS} = 100 \mu\text{A}$		1.4 V to 3.6 V			0.2		
		$I_{OLS} = 2 \text{ mA},$	V <sub>IL</sub> = 0.49 V	1.4 V			0.4		
$V_{OL}$		$I_{OLS} = 4 \text{ mA},$	V <sub>IL</sub> = 0.57 V	1.65 V		0.45			
		$I_{OLS} = 8 \text{ mA},$	V <sub>IL</sub> = 0.7 V	2.3 V			0.55		
		I <sub>OLS</sub> = 12 mA,	V <sub>IL</sub> = 0.8 V	3 V			0.7		
I	Control inputs	$V_I = V_{CC}$ or GND		3.6 V			±2.5	μΑ	
I <sub>off</sub>		$V_{I} \text{ or } V_{O} = 3.6 \text{ V}$		0			±10	μΑ	
$I_{OZ}^{(2)}$		$V_O = V_{CC}$ or GND		3.6 V			±12.5	μΑ	
I <sub>CC</sub>		$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	3.6 V			40	μΑ	
(	Control innute	V V or CND		2.5 V		3.5		~F	
C <sub>i</sub>	Control inputs	$V_I = V_{CC}$ or GND		3.3 V		3.5		pF	
•	A or D porto	V V or CND		2.5 V		8.5		"F	
C <sub>io</sub>	A or B ports	$V_O = V_{CC}$ or GND	or GND			8.5		pF	

## **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2 through Figure 5)

			V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.		UNIT	
			TYP	MIN MAX	MIN	MAX	MIN	MAX	MIN	MAX		
$f_{clock}$	Clock freque	ency				75		125		175	MHz	
t <sub>w</sub>	Pulse durati	on, CLK high or low			5.8		5		3.5		ns	
		A data before CLK↑	4.7	3.9	2.6		2.1		1.9			
		B data before CLK↑	6.2	4.3	3		2.1		1.9			
t <sub>su</sub> Setup time	SEL before CLK↑	4.5	3.4	2.2		1.6		1.3		ns		
su	Cotap umo	CLKENA1 or CLKENA2 before CLK↑	0.9	0.9	1		1.1		1.1		113	
		OE before CLK↑	5.4	5.3	2		1.6		1.1			
		A data after CLK↑	1.9	2	1.2		1.1		1			
		B data after CLK↑	0.4	1.3	0.5		0.6		0.7			
t.	Hold time	SEL after CLK↑	1	1	0.4		0.3		0.4		ns	
"	CLKENA1 or CLKENA2 after CLK↑	2.6	2.2	1.4		1.1		1	_	113		
		OE after CLK↑	0.4	0.4	0.4		0.5		0.3			

Typical values are measured at  $T_A = 25^{\circ}\text{C}$ . For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.

## SN74AVC16269 12-BIT TO 24-BIT REGISTERED BUS EXCHANGER WITH 3-STATE OUTPUTS





## **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2 through Figure 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.1		V <sub>CC</sub> = ± 0.2		V <sub>CC</sub> = ± 0.3		UNIT
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>						75		125		175		MHz
	CLK	В	13.5	3	9.5	2.5	6.7	1.6	4	1.1	3	20
<sup>L</sup> pd	t <sub>pd</sub> CLK	Α	11.6	2.6	7.4	2.2	5.8	1.5	3.5	1	2.7	ns
	CLK	В	16	3.5	12	2.4	8.5	2.1	4.8	1.5	3.8	20
t <sub>en</sub> CLK		Α	14.2	3.2	9.3	2	6.7	2	4.4	1.4	3.4	ns
	CLK	В	16	4.9	12.3	3.3	8.5	1.9	4.8	1.3	3.7	20
t <sub>dis</sub>	CLK	Α	11.9	3	8.7	2.1	6.7	1.8	3.6	1.7	3.4	ns

## Switching Characteristics<sup>(1)</sup>

 $T_A = 0$ °C to 85°C,  $C_L = 0$  pF

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 3 ± 0.1	3.3 V 5 V	UNIT
	(IIAFO1)	(001701)	MIN	MAX	
	CLK	В	1.4	2.4	20
ι <sub>pd</sub>	CLK	А	1.2	2.1	ns

<sup>(1)</sup> Texas Instruments SPICE simulation data

## **Operating Characteristics**

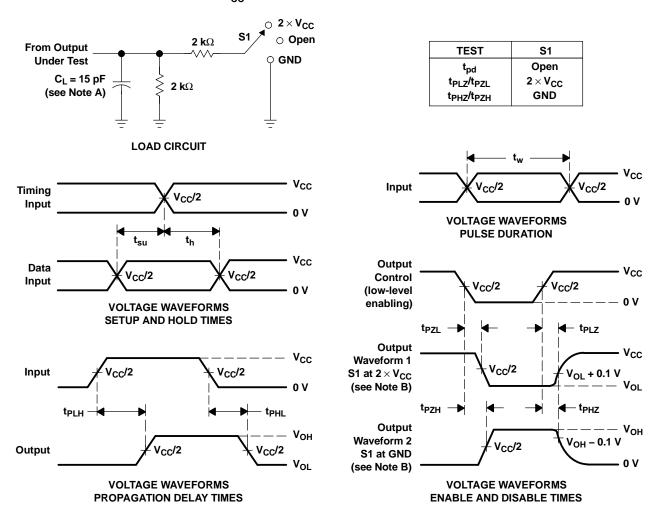
 $T_A = 25^{\circ}C$ 

	PARAMETE	R	TEST	CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
<u> </u>	Power dissipation	Outputs enabled	C - 0	f = 10 MHz	133	145	168	pF
C <sub>pd</sub>	capacitance	Outputs disabled	$C_L = 0$ ,	T = TO MINZ	102	109	124	рг





# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.2 \text{ V}$ AND 1.5 V $\pm$ 0.1 V

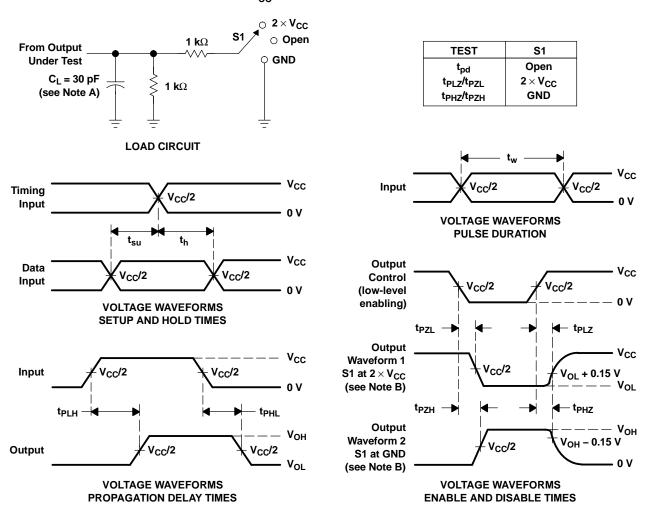


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



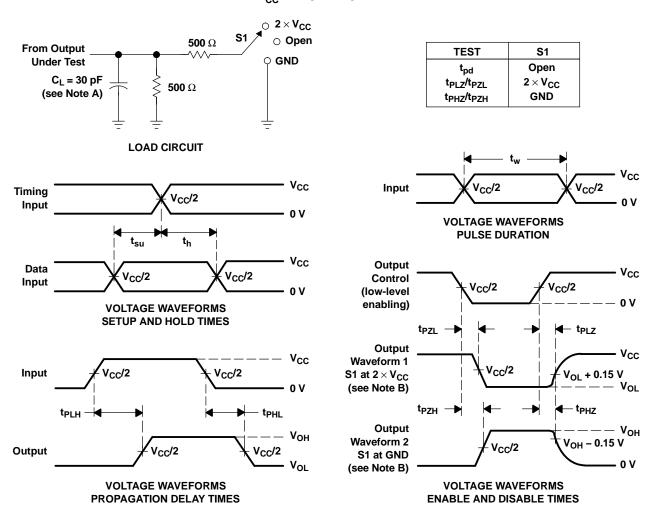
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms





# PARAMETER MEASUREMENT INFORMATION V<sub>CC</sub> = 2.5 V ± 0.2 V

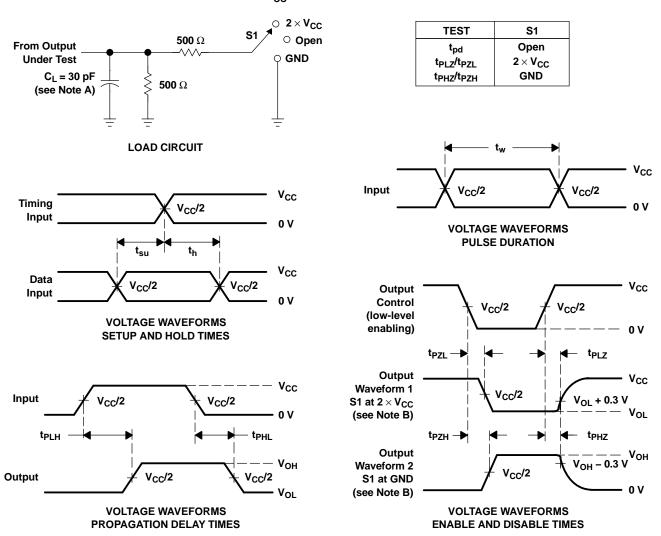


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 4. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$



- NOTES: A. C<sub>1</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 5. Load Circuit and Voltage Waveforms





20-Aug-2011

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
74AVC16269DGGRE4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74AVC16269DGGRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74AVC16269DGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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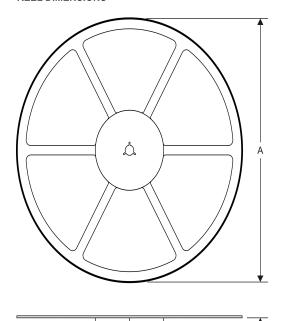
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## PACKAGE MATERIALS INFORMATION

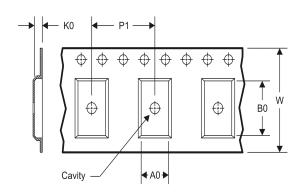
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## TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**



### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16269DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16269DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0

## DGG (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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